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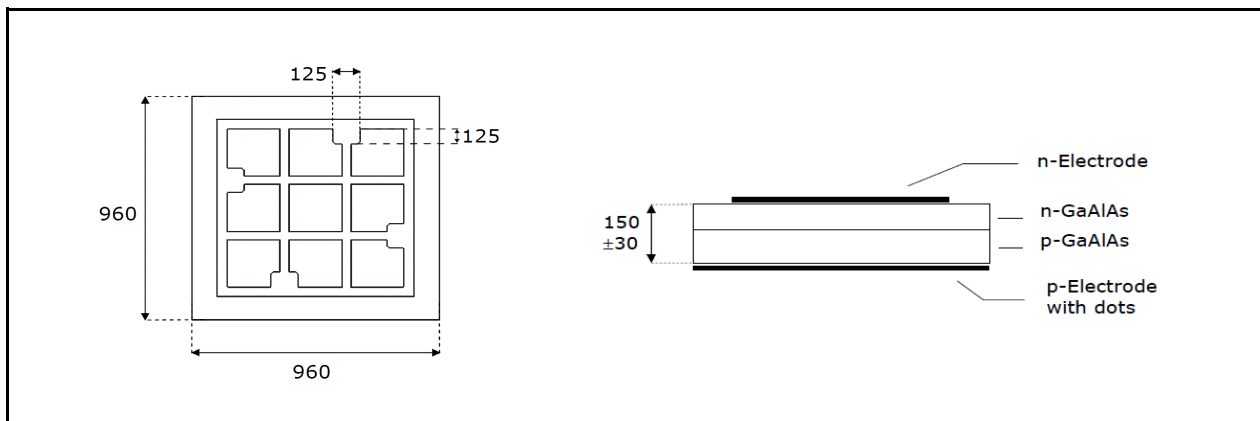
Data Sheet

LED Chip deep red

EOLC-670-21

Rev. 03, 2017

Radiation	Type	Electrodes
deep red	AlGaAs / AlGaAs, DDH	N (cathode) up



Optical and Electrical Characteristics

$T_{amb} = 25^{\circ}\text{C}$, unless otherwise specified

Parameter	Test cond.	Symbol	Min	Typ	Max	Unit
Forward voltage	$I_F = 100 \text{ mA}$	V_F		1.8	1.95	V
Forward voltage	$I_F = 350 \text{ mA}$	V_F		1.95	2.2	V
Reverse current	$V_R = 5 \text{ V}$	I_R			100	μA
Radiant power	$I_F = 100 \text{ mA}$	Φ_e	6	8		mW
Peak wavelength	$I_F = 100 \text{ mA}$	λ_p	660	670	680	nm
FWHM	$I_F = 100 \text{ mA}$	$\Delta\lambda_{0.5}$		23		nm
Switching times	$I_F = 100 \text{ mA}$	t_r, t_f		50; 35		ns

*Measured on bare chip on TO-39 header

Packing

Chips on adhesive film with wire bond side up

Art. No. 112 024



We reserve the right to make changes to improve technical design and may do so without further notice. Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer.